

Artificial intelligence enabler, high performance 8x8 multizone Time-of-Flight (ToF) sensor



Product status link

VL53L8CH

Features

- Compact and normalized histogram (CNH) data output for AI
 - Multizone data output up to 64 separate zones
 - Histogram output with signal count for each bin
 - Histogram size programmable up to 128 bins
 - Minimum bin width down to 37 mm
 - Maximum frequency up to 30 Hz through I²C or SPI
 - Ambient IR light level reported for each zone
 - All Time-of-Flight (ToF) processed data (distance, signal amplitude, reflectance etc.) are available, in addition to CNH
- Highly configurable CNH in order to meet user expectations
 - 64 zones with 18 bins at 15 Hz
 - 32 zones with 36 bins at 15 Hz
 - 16 zones with 48 bins at 25 Hz
- Wide ToF sensor with 65° field of view (FoV)
 - 45° x 45° square FoV (65° diagonal)
 - Autonomous low-power mode with interrupt programmable thresholds to wake up the host
 - Up to 400 cm ranging
 - Motion indicator for each zone to detect if targets have moved and how they have moved
- Fully integrated miniature module
 - Emitter: 940 nm invisible-light vertical-cavity surface-emitting laser (VCSEL)
 - Diffractive optical elements (DOE) on both transmitter and receiver enabling square FoV
 - Receiving array of single photon avalanche diodes (SPADs)
 - Low-power microcontroller running firmware
 - Size: 6.4 x 3.0 x 1.75 mm
- Easy integration
 - Single reflowable component
 - Requires 1.8 V core supply and 3.3 V AVDD supply
 - Optional 1.2 V or 1.8 V IOVDD interface voltage levels
 - I²C (up to 1 MHz) or SPI (up to 3 MHz) interface
 - Compatible with wide range of cover glass materials
 - Driver compatible with VL53L7CH
 - Pin-to-pin compatible with VL53L8CX



Application

- Al applications requiring multizone raw data
- Cup rim detection for coffee machines and beverage dispensers
- Floor sensing for robotics and vacuum cleaners
- Gesture motion and hand posture recognition
- People counting for smart buildings and smart homes

Description

The VL53L8CH is the perfect Time-of-Flight sensor enabling AI applications, with enhanced performance under ambient light with a wide 65° diagonal FoV. The compact and normalized histogram (CNH) innovative data output is specially designed for artificial intelligence (AI) applications requiring multizone raw data from a high performance multizone ToF sensor.

The IR signal measured in each zone is sent as raw data to the host through each bin of the histogram. Highly configurable, the user can program the resolution of the VL53L8CH up to 64 zones (8x8 zones), modify the histogram resolution up to 128 bins, and define the bin width. All this CNH data is transmitted to the host through I²C or SPI, up to 30 Hz, in addition to the standard processed data of the ToF sensor (ranging distance, signal level, reflectance etc.).

The CNH data transform STMicroelectronics' Time-of-Flight ranging sensor into a versatile optical sensor, which can enable endless Al-based applications. This CNH raw data sent to the host, on top of the standard ranging data, opens the door to many new applications beyond simple distance measurements. From solid material (carpet, wood, glass, mirror...) to gas or liquid (water, oil, chemical...), it becomes possible to detect the location and the size of a cup in a coffee machine or beverage dispenser, to sense the floor material for robotics, and develop advanced shape, motion, or hand posture recognition.

The VL53L8CH integrates a powerful new generation VCSEL, and two advanced metasurface lenses. The integrated VCSEL emits fully invisible 940 nm IR light, which is Class 1 certified and safe for the eyes.

DS14310 - Rev 3 page 2/44



1 Acronyms and abbreviations

Acronym/abbreviation	Definition	
AF	autofocus	
API	application programming interface	
AR/VR	augmented reality/virtual reality	
DOE	diffractive optical element	
ESD	electrostatic discharge	
FoV	field of view	
Fol	field of illumination	
GPIO	general-purpose input/output	
HP	high power	
I ² C	inter-integrated circuit (serial bus)	
LAF	laser autofocus	
LGA	land grid array	
LP	low power	
MCLK	main serial clock	
MISO	main input secondary output	
MOSI	main output secondary input	
NCS	chip select	
NVM	non-volatile memory	
PCB	printed circuit board	
PDAF	phase detection autofocus	
PLL	phase-locked loop	
PVT	process, voltage, and temperature	
POR	power on reset	
RAM	random-access memory	
SPAD	single photon avalanche diode	
SW	software	
ToF	Time-of-Flight	
UI	user interface	
UM	user manual	
VCSEL	vertical-cavity surface-emitting laser	

DS14310 - Rev 3 page 3/44



2 Product overview

2.1 Technical specifications

Table 1. Technical specifications

Feature	Detail		
Package	Optical LGA16		
Size	6.4 x 3.0 x 1.75 mm		
Ranging	2 to 400 cm per zone		
	AVDD: 3.3 V		
Operating voltage	CORE_1V8: 1.8 V		
	IOVDD: 1.2/1.8 V		
Operating temperature	-30 to 85°C		
Sample rate	Up to 60 Hz		
Infrared emitter	940 nm		
I ² C and SPI interface	I ² C: 1 MHz serial bus, address: 0x52		
Inc and SPI Interface	SPI: 3 MHz		
Operating ranging mode	Continuous or autonomous (see UM3183 for more information)		

2.2 Field of view

The Rx (or collector) exclusion zone includes all module assembly tolerances. It is used to define the cover glass dimensions. The cover glass opening must be equal to or wider than the exclusion zone.

The detection volume represents the applicative or system FoV in which a target is detected, and a distance measured. The Rx lens or the Rx aperture determines the detection volume. It is narrower than the exclusion zone.

Figure 1. System FoV and exclusion zone description (not to scale)

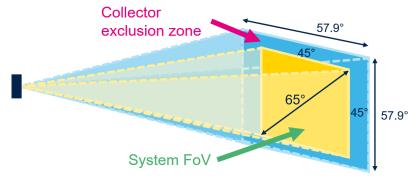


Table 2. FoV angles

	Horizontal	Vertical	Diagonal
Detection volume	45°	45°	65°
Collector exclusion zone	57.9°	57.9°	86.6°

Note:

The detection volume depends on the following: environment and sensor configuration, target distance, reflectance, ambient light level, sensor resolution, sharpener, ranging mode, and integration time.

DS14310 - Rev 3 page 4/44



Note:

The detection volume of Table 2. FoV angles has been measured with a white 88% reflectance perpendicular target. This measurement was taken:

- In full FoV
- Located at 1 m from the sensor
- Without ambient light (dark conditions)
- With an 8x8 resolution
- With a 14% sharpener (default value)
- In continuous mode
- At 15 Hz

2.3 Field of illumination

The VCSEL field of illumination (FoI) is shown in the figure below. The relative emitted signal power depends on the FoI angle. It corresponds to:

- 43.4° x 43.4°, considering a beam with a 75% signal from the maximum.
- 57.9° x 57.9°, considering a beam with a 10% signal from the maximum.

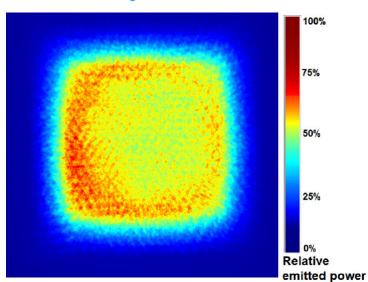


Figure 2. VL53L8CH Fol

DS14310 - Rev 3 page 5/44



2.4 System block diagram

ToF module ToF silicon Single Photon Avalanche Diode (SPAD) SCL GND **Detection array** ROM SDA AVDD Non Volatile Memory RAM INT IOVDD Microcontroller Advanced Ranging Core VCSEL Driver IR+ 940nm

Figure 3. VL53L8CH block diagram

2.5 Device pinout

Figure 4. VL53L8CH pinout (bottom view) shows the pinout of the VL53L8CH.

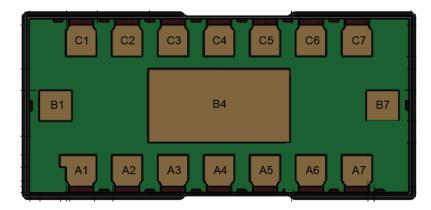


Figure 4. VL53L8CH pinout (bottom view)

The VL53L8CH pin description for the I²C and SPI configuration is given in Table 3. VL53L8CH pin description for I²C and SPI configuration. For the pins that support both I²C and SPI protocol, the I²C description is listed first and the SPI second.

DS14310 - Rev 3 page 6/44



Table 3. VL53L8CH pin description for I²C and SPI configuration

Pin number	Signal name	Signal type	Signal description
A1	INT	Digital input/output (I/O)	Interrupt output, defaults to open drain output (tristate), 47 k Ω pullup resistor to IOVDD required
A2	LPn	Digital input	Enables communication. Drive this pin to logic 0 to disable I²C communication when the device is in low-power mode. Drive this pin to logic 1 to enable I²C communication in low-power mode. This pin is typically used when you need to change the I²C address in multidevice systems. If it is not used, or if interfacing via the SPI, connect to IOVDD with a 47 k Ω pullup resistor.
A3	IOVDD	Power	1.2 V or 1.8 V I/O supply
A4	SDA / MOSI	Digital input/output (I/O)	I ² C: Data (bidirectional), 2.2 kΩ pullup resistor required to IOVDD SPI: Main output secondary input
A5	SCL/MCLK	Digital input	I ² C: Clock (input), 2.2 kΩ pullup resistor required to IOVDD SPI: Main clock
A6	RSVD1	Reserved	Connect to ground
A7	RSVD2	Reserved	Connect to ground
B1	SYNC	Digital input/output (I/O)	General purpose I/O, defaults to open drain output (tristate), 47 kΩ pullup resistor required to IOVDD
B4	THERMALPAD	Ground	Connect to a ground plane to allow good thermal conduction
В7	CORE_1V8	Power	1.8 V analog core supply
			I²C: Low value selects I²C mode - Connect to GND with 47 kΩ pulldown resistor.
C1	SPI_I2C_N	Digital input	Also used as I ² C interface reset pin, active high. Toggle this pin from 0 to 1, then back to 0 to reset the I ² C target.
			SPI : Connect to IOVDD with 47 kΩ pullup resistor
C2	NCS	Digital input	I ² C : Not used - Connect to GND with 47 kΩ pulldown resistor
02	NOS	Digital input	SPI : Active low chip select. 47 kΩ pullup resistor required to IOVDD
C3	GND	Ground	Ground
C4	AVDD	Power	3.3 V analog and VCSEL supply
			I ² C: Do not connect
C5	MISO	Digital output	SPI: Main input secondary output. Push-pull driven to IOVDD level
C6	RSVD3	Reserved	Connect to ground
C7	Ground	Ground	Ground

Note: The THERMALPAD pin has to be connected to ground (for more information refer to the AN5897).

Note: All digital signals must be driven to the IOVDD level.

Note: Toggling the I2C_RST pin resets the sensor I²C communication only. It does not reset the sensor itself. To reset

the sensor, refer to the sensor reset management procedure (UM3183).

DS14310 - Rev 3 page 7/44



2.6 Application schematics

Figure 5. Typical application schematic for I²C shows the application schematic of the VL53L8CH in I²C protocol configuration.

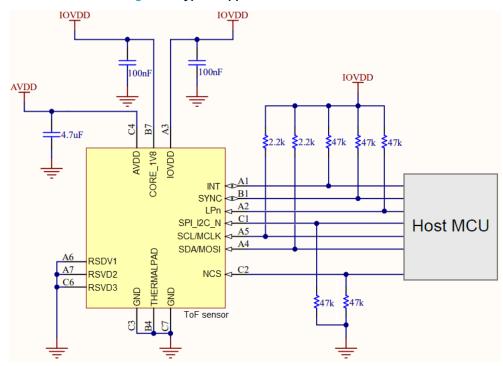


Figure 5. Typical application schematic for I²C

Note: Capacitors on the external supplies (AVDD, CORE_1V8, and IOVDD) should be placed as close as possible to the module pins.

Note: IOVDD must be set to ensure the host and the VL53L8CH operate at the same voltage levels for direct interfacing.

Figure 6. Typical application schematic for SPI shows the application schematic of the VL53L8CH in SPI protocol configuration.

DS14310 - Rev 3 page 8/44



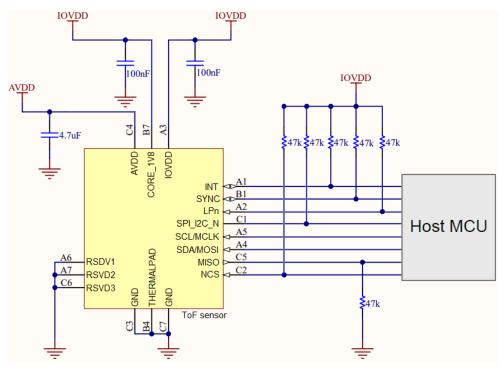


Figure 6. Typical application schematic for SPI

Note: Capacitors on the external supplies (AVDD, CORE_1V8, and IOVDD) should be placed as close as possible to the module pins.

Note: IOVDD must be set to ensure the host and the VL53L8CH operate at the same voltage levels for direct interfacing.

DS14310 - Rev 3 page 9/44

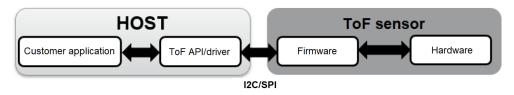


3 Functional description

3.1 Software interface

This section describes the software interface of the device. The host customer application controls the VL53L8CH using an application programming interface (API). The API implementation is delivered to the customer as a driver (C code and reference Linux® driver). The driver provides the customer application with a set of high level functions that allow control of the VL53L8CH firmware. This includes control of items such as device initialization, ranging start/stop, and mode select.

Figure 7. VL53L8CH system functional description



3.2 Power state machine

Figure 8. Power state machine

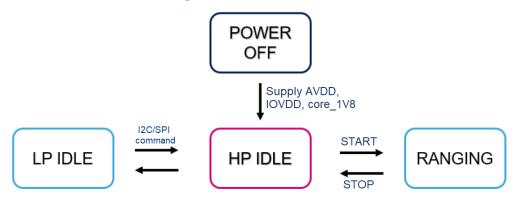


Table 4. Power state description

Device state	Description		
	LP (low-power) idle state with data retention		
L D idlo	RAM and register content retained		
LP idle	Allow fast resume to HP (high-power)		
	I ² C communication disabled if using LPn		
	HP idle state		
HP idle	Device needs to be in HP idle state to start ranging		
	Power up state		
Danging	Full operation		
Ranging	VCSEL is active (pulsing)		

DS14310 - Rev 3 page 10/44



3.3 Power up sequence

The VL53L8CH requires three power supplies:

- CORE 1V8: Analog core supply fixed at 1.8 V.
- AVDD: Analog and VCSEL supply fixed at 3.3 V.
- IOVDD: Voltage supply to the IO, which may be either 1.2 V or 1.8 V depending on the system it is integrating with. If IOVDD is 1.8 V, then the same supply may be used for both IOVDD and CORE_1V8.

When powering up the device, the three supplies should be applied at the same time.

When powering down the device, the three supplies should be removed at the same time.

To ensure proper operation of the module, the following minimum slew rates on the supplies (see Figure 9. Power up slew) must be met. This ensures correct operation of the power on the reset circuitry. The circuitry triggers at 0.9 V. However, the supplies should reach their operation levels in accordance with the slew rates listed in Table 5. Supply slew minimum limits.

Figure 9. Power up slew



Note: The minimum reset time is the minimum time required for the device RAM to load and boot up after CORE_1V8

reaches the power-on reset rising threshold. The supply must have reached the minimum operating level (1.6 V)

within this time.

Note: The AVDD rise time is determined by the internal analog levels, which must be stable for correct operation.

Note: CORE_1V8 and IOVDD are assumed to be the same supply (1V8) in Figure 9. Power up slew. If using 1V2, then IOVDD should be applied at the same time as the other supplies.

Table 5. Supply slew minimum limits

Supply status	AVDD slew	CORE_1V8 slew	IOVDD slew
Start together	0.001 V/μs	0.012 V/μs	0.012 V/μs
AVDD stable followed by CORE_1V8 and IOVDD	_	0.012 V/μs	0.012 V/μs
CORE_1V8 stable followed by AVDD and IOVDD	0.001 V/μs	_	0.012 V/μs
IOVDD stable followed by AVDD and CORE_1V8	0.001 V/μs	0.012 V/μs	_

DS14310 - Rev 3 page 11/44



4 I²C control interface

This section specifies the control interface. The I²C interface uses two signals: serial data line (SDA) and serial clock line (SCL). Each device connected to the bus uses a unique address and a simple controller/target relationship exists.

Both SDA and SCL lines are connected to a positive supply voltage using pull-up resistors located on the host. Lines are only actively driven low. A high condition occurs when lines are floating and the pull-up resistors pull lines up. When no data is transmitted both lines are high.

The controller device performs the clock signal (SCL) generation and initiates data transfer. The I²C bus on the VL53L8CH has a maximum speed of 1 Mbits/s and uses a device 8-bit address of 0x52.

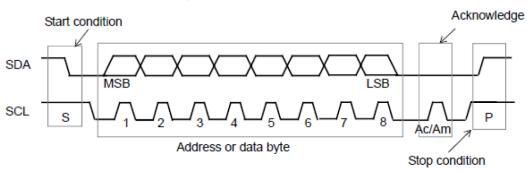


Figure 10. Data transfer protocol

Information is packed in 8-bit packets (bytes) always followed by an acknowledge bit, Ac for VL53L8CH acknowledge and Am for controller acknowledge (host bus controller). The internal data is produced by sampling SDA at a rising edge of SCL. The external data must be stable during the high period of SCL. The exceptions to this are start (S) or stop (P) conditions when SDA falls or rises respectively, while SCL is high.

A message contains a series of bytes preceded by a start condition and followed by either a stop or repeated start (another start condition but without a preceding stop condition) followed by another message. The first byte contains the device address (0x52) and also specifies the data direction. If the least significant bit is low (that is, 0x52) the message is a controller-write-to-the-target. If the lsb is set (that is, 0x53) then the message is a controller-read-from-the-target.

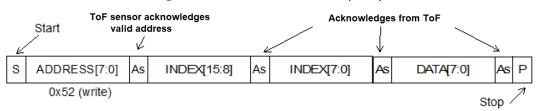
MSBit LSBit

0 1 0 1 0 0 1 R/W

Figure 11. VL53L8CH I2C device address: 0x52

All serial interface communications with the Time-of-Flight sensor must begin with a start condition. The VL53L8CH module acknowledges the receipt of a valid address by driving the SDA wire low. The state of the read/write bit (Isb of the address byte) is stored and the next byte of data, sampled from the SDA, can be interpreted. During a write sequence, the second byte received provides a 16-bit index, which points to one of the internal 8-bit registers.

Figure 12. VL53L8CH data format (write)



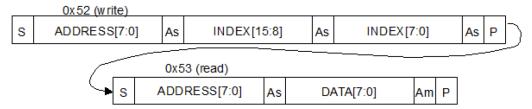
DS14310 - Rev 3 page 12/44



As data are received by the target, they are written bit by bit to a serial/parallel register. After each data byte has been received by the target, an acknowledge is generated, the data are then stored in the internal register addressed by the current index.

During a read message, the contents of the register addressed by the current index is read out in the byte following the device address byte. The contents of this register are parallel loaded into the serial/parallel register and clocked out of the device by the falling edge of SCL.

Figure 13. VL53L8CH data format (read)



At the end of each byte, in both read and write message sequences, an acknowledge is issued by the receiving device (that is, the VL53L8CH for a write and the host for a read).

A message can only be terminated by the bus controller, either by issuing a stop condition or by a negative acknowledge (that is, not pulling the SDA line low) after reading a complete byte during a read operation.

The interface also supports autoincrement indexing. After the first data byte has been transferred, the index is automatically incremented by 1. The controller can therefore send data bytes continuously to the target until the target fails to provide an acknowledge or the controller terminates the write communication with a stop condition. If the autoincrement feature is used, the controller does **not** have to send address indexes to accompany the data bytes.

Figure 14. VL53L8CH data format (sequential write)

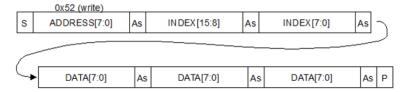
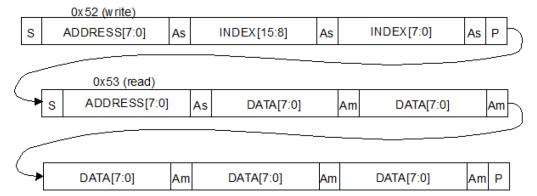


Figure 15. VL53L8CH data format (sequential read)



DS14310 - Rev 3 page 13/44



4.1 I²C interface - timing characteristics

Timing characteristics are shown in Table 6. I²C interface - timing characteristics for fast mode plus (1 MHz) and Table 7. I²C interface - timing characteristics for fast mode (400 kHz). Refer to Figure 16. I²C timing characteristics for an explanation of the parameters used.

Timings are given for all process, voltage, and temperature (PVT) conditions.

Table 6. I²C interface - timing characteristics for fast mode plus (1 MHz)

Symbol	Parameter	Minimum	Typical	Maximum	Unit
F _{I2C}	Operating frequency	0	_	1000	kHz
t _{LOW}	Clock pulse width low	0.5	_	_	μs
t _{HIGH}	Clock pulse width high	0.26	_	_	μs
t _{SP}	Pulse width of spikes, which are suppressed by the input filter	_	_	50	ns
t _{BUF}	Bus free time between transmissions	0.5	_	_	μs
t _{HD.STA}	Start hold time	0.26	_	_	μs
t _{SU.STA}	Start setup time	0.26	_	_	μs
t _{HD.DAT}	Data in hold time	0	_	0.9	μs
t _{SU.DAT}	Data in setup time	50	_	_	ns
t _R	SCL/SDA rise time	_	_	120	ns
t _F	SCL/SDA fall time	_	_	120	ns
t _{SU.STO}	Stop setup time	0.26	_	_	μs
Ci/o	Input/output capacitance (SDA)	_	_	10	pF
Cin	Input capacitance (SCL)	_	_	4	pF
CL	Load capacitance (1V8)	_	140	550	pF
) OL	Load capacitance (1V2)	_	140	150	pF

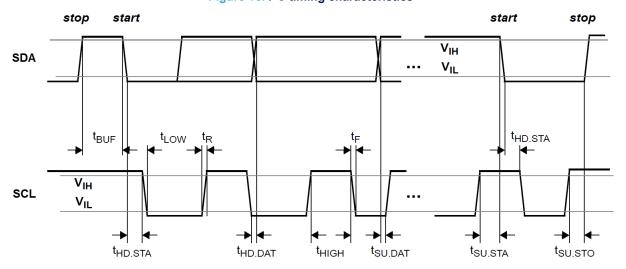
DS14310 - Rev 3 page 14/44



Table 7. I²C interface - timing characteristics for fast mode (400 kHz)

Symbol	Parameter	Minimum	Typical	Maximum	Unit
F _{I2C}	Operating frequency	0	_	400	kHz
t_{LOW}	Clock pulse width low	1.3	_	_	μs
t _{HIGH}	Clock pulse width high	0.6	_	_	μs
t _{SP}	Pulse width of spikes, which are suppressed by the input filter	_	_	50	ns
t _{BUF}	Bus free time between transmissions	1.3	_	_	μs
t _{HD.STA}	Start hold time	0.26	_	_	μs
t _{SU.STA}	Start setup time	0.26	_	_	μs
t _{HD.DAT}	Data in hold time	0	_	0.9	μs
t _{SU.DAT}	Data in setup time	50	_	_	ns
t _R	SCL/SDA rise time	_	_	300	ns
t _F	SCL/SDA fall time	_	_	300	ns
t _{SU.STO}	Stop setup time	0.6	_	_	μs
Ci/o	Input/output capacitance (SDA)	_	_	10	pF
Cin	Input capacitance (SCL)	_	_	4	pF
CL	Load capacitance (1V8)	_	125	400	pF
ΟL	Load capacitance (1V2)	_	125	400	pF

Figure 16. I²C timing characteristics



DS14310 - Rev 3 page 15/44



5 SPI timing specification

This section specifies the SPI control interface used to control data transfer.

The communication interface is based on a 4-wire, serial, synchronous interface between the host (controller) and the VL53L8CH (target device). Refer to the schematics in Section 2.6 Application schematics. The 4-wire interface comprises the following four signals:

- NCS: Chip select (active low)
- MCLK: Main serial clock
- MOSI: Main output secondary input, data output from controller
- MISO: Main input secondary output, data output from target

All signals are CMOS inputs/outputs. Their levels are in line with the IOVDD supply. The SPI modes supported are clock polarity = 1 and clock phase = 1. These modes correspond to data captured on a clock's rising edge and data propagated on a falling edge. The controller selects the target device with the NCS. The NCS enables target transmission. It is an active low signal. After the device is selected with the falling edge of the NCS, an 8-bit command can be received. If the VL53L8CH has not been activated using the NCS chip select line, the MCLK input clock and MOSI signals are disregarded.

The falling edge (high to low transition) of the NCS signal is required to initiate an action. The transmission ends with the rising edge (low-to-high transition). This causes the end of data transfer, and resets the internal counter and command registers. All this reinitializes the serial communication.

While the register address is applied on the MOSI pin, the same information is mirrored on the MISO pin.

The NCS can be reset to a noncommunication state (high) at any time, including during a transaction. Should this happen, the device resets its internal state machine. Consequently, any ongoing communications are aborted. No internal changes to the registers occur, and the interface is ready to receive a new transaction again. However, the SPI target can tolerate the MCLK being interrupted. It can resume at any point in time, without specific duration limit.

During each SPI clock cycle, a full duplex data transmission occurs. The MOSI input is the data signal, provided by the host to the device. It carries both the address and data information in write mode. Only address information is in read mode. The controller sends a bit on the MOSI line and the target reads it. Concurrently, the target sends a bit on the MISO line and the controller reads it. This sequence is maintained even when only one-directional data transfer is intended.

The MISO output is the data signal, provided by the device to the host. It carries the data in read mode only, and the mode register content during the address setup. Any internal register that can be written to, can also be read from. There are also read-only registers that contain device status information. For example, design revision details. A read instruction from an unused register location returns the value 0x00. A read instruction from the manufacturer's specific registers may return any value. A write instruction to a reserved or unused register location is illegal. The effect of such a write is ignored. Transmission may continue for any number of clock cycles. When complete, the controller stops toggling the clock signal, and typically deselects the target.

DS14310 - Rev 3 page 16/44

Parameter	Symbol	Min.	Max.	Unit	Notes
Operating frequency	Fspi	_	3	MHz	MCLK
Time from NCS active and MCLK falling edge	Tncs_to_clk	0	_	ns	
Rise/Fall time on MISO	TriseFallMiso	_	3	ns	With 20 pF load max
Duty cycle	Duty	40	60	%	
Time from MOSI stable to MCLK rising edge	Tmosi_to_clk	16	_	ns	
Time MOSI must remain stable after MCLK rising edge	Tclk_to_ncs	16	_	ns	
Time from last MCLK rising edge to NCS going inactive	Tclk to dat	0	_	ns	
Propagation delay from falling MCLK edge to MISO data valid	GR_IO_Uat	_	20	ns	With 20 pF load max

Table 8. SPI interface timing specification

5.1 SPI write messages

The write timing sequence is shown in Figure 17. SPI writing timing sequence. Once the NCS selects the device, the controller sends a write command to the VL53L8CH. The controller then provides a clock to output the status. The writing sequence starts with the MOSI initial value equal to 1. The address is sent first, and the data is sent afterwards. The most significant bit is sent first (big-endian format). The address length is 15 bits. Data length is 8 bits.

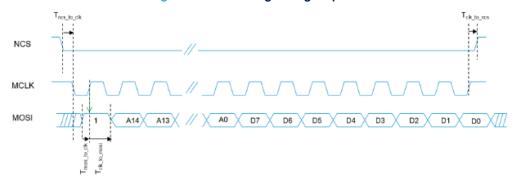


Figure 17. SPI writing timing sequence

If the host continues to transmit data beyond the first 8 data bits, then the target goes into autoincrement write mode. The autoincrement write timing sequence is shown in Figure 18. SPI autoincrement write sequence. The MOSI initial value is 1. The address is incremented automatically and internally by the target. Subsequent data bits correspond to incrementing addresses.

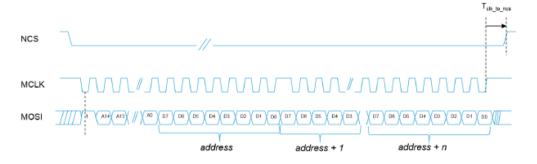


Figure 18. SPI autoincrement write sequence

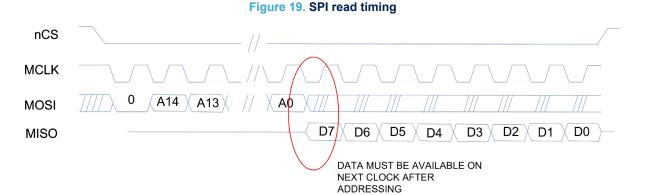
DS14310 - Rev 3 page 17/44



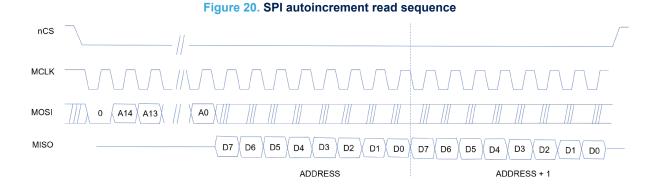
5.2 SPI read messages

The controller sends the read command to the VL53L8CH. The controller then provides a clock to output the

In read mode, the target writes the data to the controller. Transmission is ended by the controller. The reading sequence starts with the first value of the MOSI equal to 0. The most significant bit is sent first (big-endian format). Once the last bit of the address has been received, the device fetches the data internally. The device then presents the data onto the MOSI pin by the next falling MCLK edge (half the MCLK period). This enables the host to sample the data on the following rising edge. Once 8 bits of data have been received, the host sets the NCS high. This terminates the process. More details of the SPI read timing are shown in Figure 19. SPI read



If the host continues to toggle the MCLK after the last data bit has been read, the target goes into autoincrement read mode. In this mode, the address is automatically incremented by the target, and the read data are transmitted sequentially to the controller on the MISO line. More details of the SPI autoincrement read mode are shown in Figure 20. SPI autoincrement read sequence.



DS14310 - Rev 3 page 18/44



6 Electrical characteristics

6.1 Absolute maximum ratings

Table 9. Absolute maximum ratings

Parameter	Min.	Тур.	Max.	Unit
AVDD	-0.5	_	3.47	
CORE_1V8	-0.5	_	1.98	V
IOVDD	-0.5	_	1.98	

Note:

Stresses above those listed above may cause permanent damage to the device. This is a stress rating only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

6.2 Recommended operating conditions

Table 10. Recommended operating conditions

Parameter	Min.	Тур.	Max.	Unit	
AVDD supply	3.13	3.3	3.47		
CORE_1V8 supply	1.62	1.8	1.98		
IOVDD supply with 1.2V configuration	1.08	1.2	1.32		
IOVDD supply with 1.8V configuration	1.62	1.8	1.98	98	
Ambient temperature (normal operation)	-30	_	85	°C	

Note: All three supplies are independent.

Note: When IOVDD is 1.8 V, it is recommended to use the same supply as CORE_1V8.

6.3 Electrostatic discharge (ESD)

The VL53L8CH is compliant with the ESD values presented in Table 11. ESD performance.

Table 11. ESD performance

Parameter	Specification	Conditions
Human body model	JEDEC JS-001-2014	± 2 kV, 1500 Ω, 100 pF
Charged body model	JEDEC JS-001-2014	± 500 V

DS14310 - Rev 3 page 19/44



6.4 Current consumption

The current consumption values are given in Table 12. Current consumption.

- Typical values quoted are for nominal voltage, process, and temperature (23°C).
- Maximum values are quoted for the worst case conditions (process, voltage, and temperature), unless stated otherwise (85°C)

Table 12. Current consumption

	Average current consumption						
Device state	AV	DD	CORE_1V8		IOVDD		Unit
	Тур.	Max.	Тур.	Max.	Тур.	Max.	
LP idle	55	390	0.01	0.5	0.5	2	μA
HP idle	1	1.6	3	17	0.0003	0.002	
Active ranging	43	50	50	80	0.003	0.006	mA

Note:

Active ranging is when the device is actively ranging. The current consumption is not affected by a 4x4 or 8x8 zone configuration.

- CORE_1V8 peak current is the average value +10 mA.
- AVDD peak current is the average current +10 mA.
- IOVDD peak current is the average value +10 mA.

Table 13. Example of typical power consumption in continuous mode

Parameter	AVDD 3.3 V IOVDD/CORE_1V8 1.8V	Unit
Continuous mode (4x4 or 8x8 mode)	215	mW

Table 14. Example of typical power consumption in autonomous mode

Parameter	AVDD 3.3 V IOVDD/CORE_1V8 1.8V	Unit
4x4 mode 1 Hz frame rate with 5 ms integration time	1.6	
4x4 mode 5 Hz frame rate with 5 ms integration time	12.5	mW
8x8 mode 1 Hz frame rate with 5 ms integration time	6.7	IIIVV
8x8 mode 5 Hz frame rate with 5 ms integration time	32.3	

6.5 Digital input and output

Table 15. I²C, SPI, INT, and SYNC summarize the digital I/O electrical characteristics.

Table 15. I²C, SPI, INT, and SYNC

Symbol	Parameter	IOVDD configuration	Min.	Max.	Unit
VIL	Low-level input voltage	1.2/1.8V	-0.3	0.3*IOVDD	
VIH	High-level input voltage	V1.2/1.8V	0.7*IOVDD	IOVDD + 0.3	
Vor	Low-level output voltage (IOUT = 4 mA)	1.2/1.8V	_	0.2*IOVDD	V
VoH	High-level output voltage (IOUT = 4 mA)	1.2/1.8V	0.8*IOVDD	_	

DS14310 - Rev 3 page 20/44

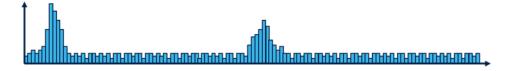


7 Histogram (CNH) output

Up to 6 KB of histogram data can be read by the host at every frame. Selection of what histogram data is placed in this 6 KB data area is highly configurable, allowing the amount of the data transferred to be optimized for different applications. The format of the collected histogram data is called compact normalized histogram (CNH):

- · Compact: Options are available to reduce the amount of data compared to the native "raw" histogram data
- Normalized: Raw data are adjusted to compensate variations caused by frame-to-frame adjustments
- Histogram: Primary data is in the form of histograms recording return-signal-strength vs range

Figure 21. Raw histogram (128 bins)



The sensor is highly configurable. The user can program the number of bins, bin width, and also the region-of-interest. Ambient light level is measured during ranging, and is later removed from the histogram data. A record of the ambient light level that was removed from each histogram is available in a separate area of the data result buffer.

Data aggregation options during preprocessing include region-of-interest and subsampling operations both spatially (zone based), and temporally (on histogram bins).

Table 16. ToF ranging core histogram characteristics

Parameter	Value	Units
Ranging core histogram bin width	250	ps
Ranging core histogram bin equivalent range	37.5	mm
Ranging core number of bins in histogram	128	bins

Table 17. CNH parameters

Setting	Value	Units
CNH buffer maximum size	6160	bytes
Bytes-per-histogram bin	5	bytes
Maximum zones per CNH aggregate	64	zones
Maximum histogram binning factor	8	_
Bytes-per-ambient level	5	bytes

Note: Details of the CNH configuration options available can be found in the user manual UM3183.

DS14310 - Rev 3 page 21/44



Table 18. Example operating configurations

Number of histograms	Bins per CNH histogram	CNH data size (bytes)	Transfer time (ms)	Framerate (fps)
8	80	3268	32	30
8	128	5188	48	20
16	48	3948	36	25
16	72	5868	54	18
32	36	6108	56	15
64	18	6108	56	15

Note:

Data transfer timing is for the I²C interface with an SCL clock at 1 MHz. CNH data size includes histogram and ambient light level data. No per-zone target data are included in the data transfer. Details of how to configure such operating modes can be found in the user manual UM3183.

Figure 22. CNH example 1 (18 bins selected, binning factor = 1)

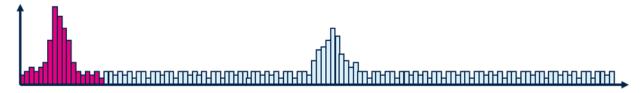
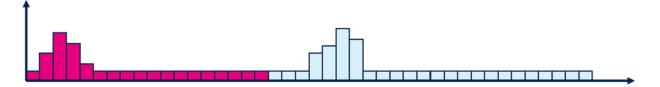


Figure 23. CNH example 2 (18 bins selected, binning factor = 3)



DS14310 - Rev 3 page 22/44



8 Ranging performances

8.1 Zone mapping

8.1.1 Zone mapping 4x4

Figure 24. Zone mapping in 4x4 mode shows the zone definition in 4x4 mode. There are 16 zones in total. They increment along a row first before starting a new row. The physical view is from the device top into the lens. The number of zones, as indicated in Figure 24. Zone mapping in 4x4 mode, corresponds to the zone IDs returned by the sensor.

8 9 10 11 15 15 15 17 0 3

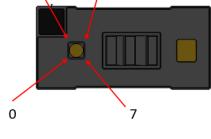
Figure 24. Zone mapping in 4x4 mode

C = Corner zones INNER = all zones not identified as the corner

8.1.2 Zone mapping 8x8

Figure 25. Zone mapping in 8x8 mode shows the zone definition in 8x8 mode. There are 64 zones in total. They increment along a row first before starting a new row. The physical view is from the device top into the lens. The number of zones, as indicated in Figure 25. Zone mapping in 8x8 mode, correspond to the zone IDs returned by the sensor to the host.

Figure 25. Zone mapping in 8x8 mode



C = Corner zones INNER = all zones not identified as the corner

DS14310 - Rev 3 page 23/44



8.1.3 Effective zone orientation

The VL53L8CH module includes a lens over the Rx aperture, which flips (horizontally and vertically) the captured image of the target. Consequently, the zone identified as zone 0, in the bottom left of the SPAD array (see Figure 26. Effective orientation), is illuminated by a target. This target is located at the top right-hand side of the scene.

SPAD array zone ID

Because of the Rx lens, zone ID 0 that is at the bottom left of the SPAD array is illuminated by the Target at the top-right side

RX TX

12 13 14 15

8 9 10 11

4 5 6 7

0 1 2 3

Resolution=16 (4x4)

Figure 26. Effective orientation

8.2 Continuous ranging mode

8.2.1 Measurement conditions

The following criteria and test conditions apply to all the characterization results detailed in this section unless specified otherwise:

- The specified target fills 100% of the FoV of the device (in all zones).
- Targets used are Munsell N4.75 (17%), Munsell N8.25 (54%), and Munsell N9.5 (88%).
- AVDD is 3.3 V, IOVDD is 1.8 V, and CORE 1V8 is 1.8 V.
- Nominal ambient temperature is 23°C.
- Maximum range capability is based on a 90% detection rate. (1)
- Range accuracy figures are based on 2.7 sigma. This means that 99.3% of measurements are within the specified accuracy.
- Tests are performed in the dark and at 2 W/m² target illumination (940 nm). A 2 W/m² target irradiance at 940 nm is equivalent to 5 kLux daylight.
- All tests are performed without cover glasses with a crosstalk margin set to 0 kcps.
- The sensor relies on default calibration data.
- The device is controlled through the API using the default driver settings.
- Detection rate is a statistical value indicating the worst case percentage of measurements that return a valid ranging. For
 example, taking 1000 measurements with a 90% detection rate, gives 900 valid distances. The 100 other distances may be
 outside the specification, or flagged with an invalid target status.

DS14310 - Rev 3 page 24/44



8.2.2 Maximum ranging distance 4x4

Table 19. Maximum ranging capabilities when ranging continuously at 30 Hz shows the maximum ranging capability of the VL53L8CH under different conditions. Refer to Section 8.2.1 Measurement conditions for the general test conditions.

Table 19. Maximum ranging capabilities when ranging continuously at 30 Hz

Target reflectance level. Full FoV (reflectance %)	Zone	Dark	Ambient light (5 kLux)
		Typical 4000 mm	Typical 2850 mm
Mhite target (990/)	Inner	Minimum 4000 mm	Minimum 2850 mm
White target (88%)	Comon	Typical 4000 mm	Typical 2850 mm
	Corner	Minimum 4000 mm	Minimum 2700 mm
	Inner	Typical 4000 mm	Typical 2600 mm
Linkt (540/)		Minimum 4000 mm	Minimum 2550 mm
Light gray target (54%)	Corner	Typical 4000 mm	Typical 2500 mm
		Minimum 4000 mm	Minimum 2400 mm
	Inner	Typical 4000 mm	Typical 1650 mm
Cro., to rest (470/)		Minimum 4000 mm	Minimum 1600 mm
Gray target (17%)	Comen	Typical 3950 mm	Typical 1550 mm
	Corner	Minimum 3900 mm	Minimum 1500 mm

8.2.3 Maximum ranging distance 8x8

Table 20. Maximum ranging capabilities when ranging continuously at 15 Hz shows the maximum ranging capability of the VL53L8CH under different conditions. Refer to Section 8.2.1 Measurement conditions for the general test conditions.

Table 20. Maximum ranging capabilities when ranging continuously at 15 Hz

Target reflectance level. Full FoV (reflectance %)	Zone	Dark	Ambient light (5 kLux)
		Typical 4000 mm	Typical 1550 mm
Mhita target (999/)	Inner	Minimum 4000 mm	Minimum 1100 mm
White target (88%)	Corner	Typical 3950 mm	Typical 1400 mm
	Corner	Minimum 2900 mm	Minimum 1100 mm
	Inner	Typical 3300 mm	Typical 1400 mm
Light grow target (E40/)		Minimum 2350 mm	Minimum 1000 mm
Light gray target (54%)		Typical 3100 mm	Typical 1250 mm
		Minimum 2100 mm	Minimum 950 mm
	Inner	Typical 2450 mm	Typical 1150 mm
Croy target (179/)		Minimum 1500 mm	Minimum 900 mm
Gray target (17%)		Typical 1950 mm	Typical 950 mm
		Minimum 1300 mm	Minimum 700 mm

DS14310 - Rev 3 page 25/44



8.2.4 Range accuracy in continuous mode

Figure 27. Range accuracy vs distance illustrates how range accuracy is defined over distance.

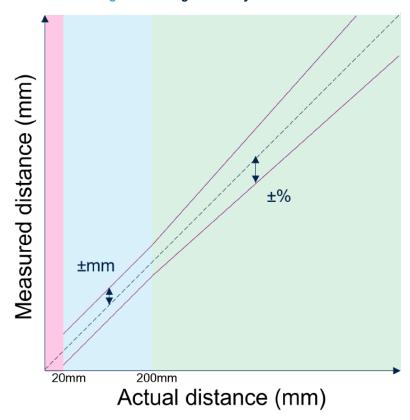


Figure 27. Range accuracy vs distance

Table 21. Range accuracy in continuous mode

Mode	Distance	Target reflectance	Dark (0 kLux)	Ambient light (5 kLux)
		White target (88%)	±10 mm	±12 mm
	20-200 mm	Light gray target (54%)	±9 mm	±11 mm
4x4 at 30 Hz		Gray target (17%)	±8 mm	±10 mm
4X4 at 50 HZ		White target (88%)	±3%	±4%
	200-4000 mm	Light gray target (54%)	±4%	±6%
		Gray target (17%)	±4%	±7%
	20-200 mm	White target (88%)	±11 mm	±10 mm
		Light gray target (54%)	±12 mm	±13 mm
8x8 at 15 Hz		Gray target (17%)	±12 mm	±14 mm
0X0 at 15 HZ		White target (88%)	±5%	±5%
	200-4000 mm	Light gray target (54%)	±5%	±6%
		Gray target (17%)	±5%	±8%

Note: The accuracy of the corner zone data compared to the center 4 zones may degrade by up to 4%.

Note: The accuracy in Table 21. Range accuracy in continuous mode assumes a correctly mounted module. Final assemblies should include additional tolerance for PCB assembly tilt, and mounting of the PCB in a product housing. Typically an additional 1~2%.

DS14310 - Rev 3 page 26/44



8.3 Autonomous ranging mode

8.3.1 Measurement conditions

The following criteria and test conditions apply to all the characterization results detailed in this section unless specified otherwise:

- The specified target fills 100% of the FoV of the device (in all zones).
- Targets used are Munsell N4.75 (17%), Munsell N8.25 (54%), and Munsell N9.5 (88%).
- AVDD is 3.3 V, IOVDD is 1.8 V, and CORE 1V8 is 1.8 V.
- Nominal ambient temperature is 23°C.
- Maximum range capability is based on a 90% detection rate. (1)
- Range accuracy figures are based on 2.7 sigma. This means that 99.3% of measurements are within the specified accuracy.
- Tests are performed in the dark and at 2 W/m² target illumination (940 nm). A 2 W/m² target irradiance at 940 nm is equivalent to 5 kLux daylight.
- All tests are performed without cover glasses with a crosstalk margin set to 0 kcps.
- The sensor relies on default calibration data.
- The device is controlled through the API using the default driver settings.
- 1. Detection rate is a statistical value indicating the worst case percentage of measurements that return a valid ranging. For example, taking 1000 measurements with a 90% detection rate, gives 900 valid distances. The 100 other distances may be outside the specification, or flagged with an invalid target status.

8.3.2 Maximum ranging distance 4x4

Table 22. Maximum ranging capabilities when ranging with autonomous mode at 1 Hz - 4x4 – integration time 5 ms shows the maximum ranging capability of the VL53L8CH under different conditions. Refer to Section 8.2.1 Measurement conditions for the general test conditions.

Table 22. Maximum ranging capabilities when ranging with autonomous mode at 1 Hz – 4x4 – integration time 5 ms

Target reflectance level. Full FoV (reflectance %)	Zone	Dark	Ambient light (5 kLux)
		Typical 4000 mm	Typical 1550 mm
Mhita target (999/)	Inner	Minimum 4000 mm	Minimum 1100 mm
White target (88%)	Corner	Typical 4000 mm	Typical 1400 mm
	Corner	Minimum 4000 mm	Minimum 1100 mm
	Inner	Typical 4000 mm	Typical 1450 mm
Light grow target (E49/)		Minimum 4000 mm	Minimum 1100 mm
Light gray target (54%)		Typical 3700 mm	Typical 1300 mm
		Minimum 3500 mm	Minimum 1100 mm
	Inner	Typical 3000 mm	Typical 1350 mm
Crowtorget (179/)		Minimum 3000 mm	Minimum 1100 mm
Gray target (17%)	Corner	Typical 2550 mm	Typical 1200 mm
	Corner	Minimum 2400 mm	Minimum 1000 mm

DS14310 - Rev 3 page 27/44



8.3.3 Maximum ranging distance 8x8

Table 23. Maximum ranging capabilities when ranging with autonomous mode at 1 Hz – 8x8 – integration time 5 ms shows the maximum ranging capability of the VL53L8CH under different conditions. Refer to Section 8.2.1 Measurement conditions for the general test conditions.

Table 23. Maximum ranging capabilities when ranging with autonomous mode at 1 Hz – 8x8 – integration time 5 ms

Target reflectance level. Full FoV (reflectance %)	Zone	Dark	Ambient light (5 kLux)
		Typical 3600 mm	Typical 1250 mm
Mhita target (999/)	Inner	Minimum 2400 mm	Minimum 1000 mm
White target (88%)	Corner	Typical 2850 mm	Typical 1150 mm
	Corner	Minimum 1700 mm	Minimum 800 mm
	Inner	Typical 2600 mm	Typical 1100 mm
Light grow target (E40/)		Minimum 1900 mm	Minimum 900 mm
Light gray target (54%)		Typical 2200 mm	Typical 1000 mm
		Minimum 1350 mm	Minimum 750 mm
	Inner	Typical 1400 mm	Typical 850 mm
Croy target (179/)		Minimum 1200 mm	Minimum 800 mm
Gray target (17%)	Corner	Typical 1350 mm	Typical 700 mm
	Corner	Minimum 900 mm	Minimum 700 mm

DS14310 - Rev 3 page 28/44



8.3.4 Range accuracy in autonomous mode

Figure 28. Range accuracy vs distance illustrates how range accuracy is defined over distance.

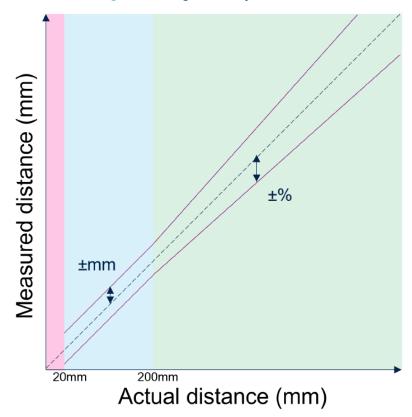


Figure 28. Range accuracy vs distance

Table 24. Range accuracy in autonomous mode

Mode	Distance	Target reflectance	Dark (0 kLux)	Ambient light (5 kLux)
		White target (88%) ±11 mm		±12 mm
	20-200 mm	Light gray target (54%)	±10 mm	±12 mm
4x4 at 1 Hz and 5 ms		Gray target (17%)	±10 mm	±14 mm
integration time		White target (88%)	±3%	±5%
	200-4000 mm	Light gray target (54%)	±4%	±6%
		Gray target (17%)	±4%	±8%
		White target (88%)	±10 mm	±10 mm
	20-200 mm	Light gray target (54%)	±10 mm	±12 mm
8x8 at 1 Hz and 5 ms		Gray target (17%)	±11 mm	±14 mm
integration time		White target (88%)	±5%	±6%
	200-4000 mm	Light gray target (54%)	±6%	±8%
		Gray target (17%)	±6%	±11%

Note: The accuracy of the corner zone data compared to the center 4 zones may degrade by up to 4%.

Note: The accuracy in Table 24. Range accuracy in autonomous mode assumes a correctly mounted module. Final assemblies should include additional tolerance for a PCB assembly tilt, and mounting of the PCB in a product housing. Typically an additional 1~2%.

DS14310 - Rev 3 page 29/44



8.4 Range offset drift over temperature

Self-heating or a change in ambient temperature increases silicon temperature. This results in a range offset drift. This may be minimized by performing a periodic autocalibration, resulting in a typical drift of 0.1 mm/°C.

The autocalibration is done automatically when a new ranging session is started. A stop/start of the device is required if the device is already streaming.

DS14310 - Rev 3 page 30/44



9 Outline drawings

The figures below give details of the VL53L8CH module. All values are given in millimetres.

STMicroelectronics delivers either of these dual-source cap assemblies to the customer since the pad and substrate design are identical for both versions. This is because the pad and substrate design are identical for both versions, and have no impact on the customer PCB design. Ranging performances, reflow, and technical parameters are identical for all module designs presented below.

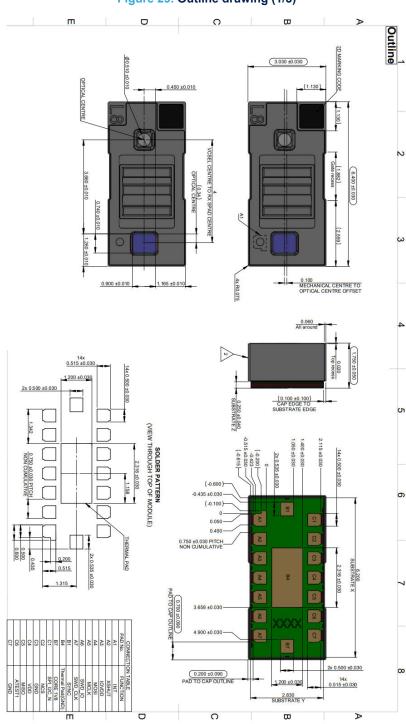


Figure 29. Outline drawing (1/3)

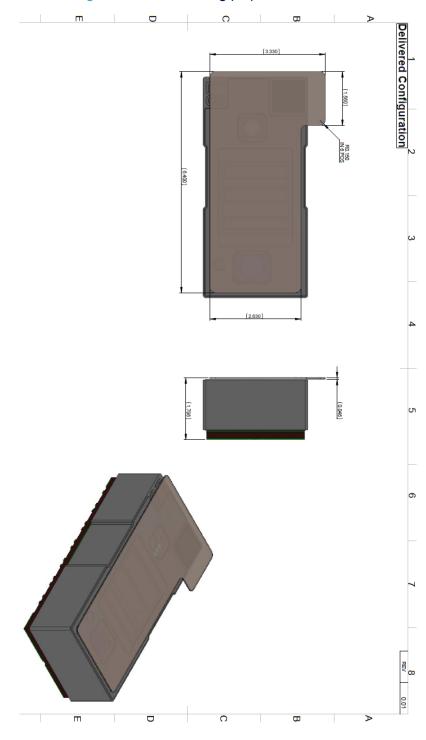
DS14310 - Rev 3 page 31/44



Note: A thermal pad is required on the application board for thermal dissipation purpose. For more information, refer to AN5897.

Note: For more information, refer to the pin description in Section 2.5 Device pinout.

Figure 30. Outline drawing (2/3) - module with liner



DS14310 - Rev 3 page 32/44

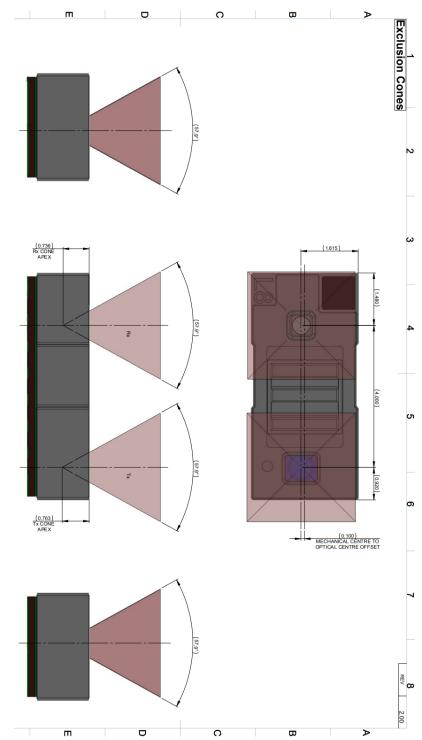


Figure 31. Outline drawing (3/3) - optical exclusion zones

DS14310 - Rev 3 page 33/44



10 Laser safety considerations

The VL53L8CH contains a laser emitter and corresponding drive circuitry. The laser output is designed to meet Class 1 laser safety limits under all reasonably foreseeable conditions including single faults in compliance with IEC 60825-1:2014.

Do not increase the laser output power by any means. Do not use any optics to focus the laser beam.

Caution:

Use of controls or adjustments, or performance of procedures other than those specified herein may result in hazardous radiation exposure.

Figure 32. Class 1 laser label



The VL53L8CH complies with:

- IEC 60825-1:2014
- 21 CFR 1040.10 and 1040.11 except for conformance with IEC 60825-1:2014 as described in Laser Notice No.56, dated May 8, 2019
- EN 60825-1:2014 including EN 60825-1:2014/A11:2021,
- EN 50689:2021 except for the requirement of clause 5 from EN50689 regarding Child Appealing Products. If designing a Child Appealing Product, please contact ST Technical Application Support.

DS14310 - Rev 3 page 34/44

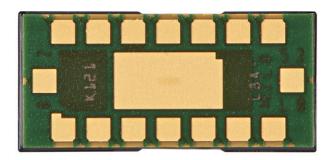


11 Packaging and labeling

11.1 Product marking

See the figure below for the product marking area. The marking is L8A-

Figure 33. Product marking area



A 2D product marking code is applied on the corner of the module cap as shown in Figure 34. 2D marking product code.

Note: The 2D marking code aligns with pin C7 of the module and is not an indicator of pin 1.





11.2 Inner box labeling

The labeling follows the Microelectronics' standard packing acceptance specification. The following information is on the inner box label:

- Assembly site
- Sales type
- Quantity
- Trace code
- Marking
- Bulk ID number

11.3 Packing

At customer/subcontractor level, it is recommended to mount the VL53L8CH in a clean environment. To help avoid any foreign material contamination at final assembly level, the modules are shipped in a tape and reel format with a protective liner. The liner is compliant with reflow at 260°C (as per JEDEC-STD-020E).

Note: The liner must be removed during assembly of the customer device, just before mounting the cover glass.

DS14310 - Rev 3 page 35/44



11.4 Tape outline drawing

0.30±0.05(T)

6.00±0.30(W) В 8.00(P1) ø1.50min.(D1) Section B-B USER FEED DIRECTION Section A-A

Figure 35. VL53L8CH tape and reel packaging drawing

11.5 Pb-free solder reflow process

Table 25. Recommended solder profile and Figure 36. Solder profile show the recommended and maximum values for the solder profile.

Customers have to tune the reflow profile depending on the PCB, solder paste, and material used. We expect customers to follow the "recommended" reflow profile, which is specifically tuned for the VL53L8CH package.

For any reason, if a customer must perform a reflow profile, which is different from the "recommended" one (especially where the peak temperature is > 240°C), the new profile must be qualified by the customer at their own risk. The profile has to be within the "maximum" profile limit described in Table 25. Recommended solder profile.

Parameters Recommended Maximum Units Minimum temperature (T_S min) 130 150 °C Maximum temperature (T_S max) 200 200 °C 90-110 60-120 Time t_s (T_S min to T_S max) s Temperature (T_L) 217 217 °C Time (t_L) 55-65 55-65 s Ramp up 2 3 °C/s Temperature (T_{p-10}) 235 °C 10 Time (t_{p-10}) s °C/s 3 Ramp up Peak temperature (Tp) °C 240 260 Time to peak 300 300 s Ramp down (peak to T_L) -4 -6 °C/s

Table 25. Recommended solder profile

DS14310 - Rev 3 page 36/44



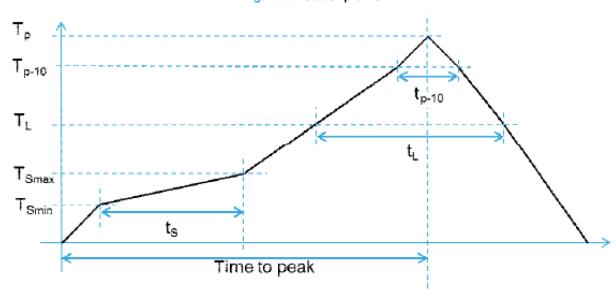


Figure 36. Solder profile

Note: The component should be limited to a maximum of three passes through this solder profile.

Note: As the VL53L8CH package is not sealed, only a dry reflow process should be used (such as convection reflow).

Vapor phase reflow is not suitable for this type of optical component.

Note: The VL53L8CH is an optical component and as such, it should be treated carefully. This typically includes using

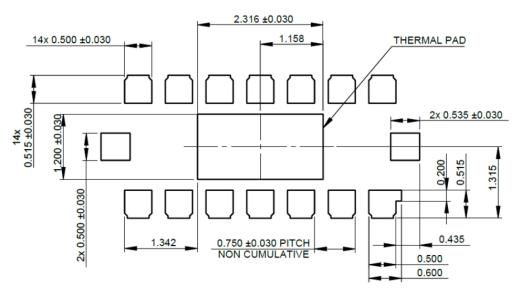
a 'no-wash' assembly process.

11.6 Handling and storage precautions

11.6.1 Recommended solder pad dimensions

Figure 37. Recommended solder pattern

SOLDER PATTERN (VIEW THROUGH TOP OF MODULE)



DS14310 - Rev 3 page 37/44



11.6.2 Shock precautions

Sensor modules house numerous internal components that are susceptible to shock damage. If a unit is subject to excessive shock, is dropped on the floor, or a tray/reel of units is dropped on the floor, it must be rejected, even if no apparent damage is visible.

11.6.3 Part handling

Handling must be done with nonmarring ESD safe carbon, plastic, or teflon tweezers. Ranging modules are susceptible to damage or contamination. The customer is advised to use a clean assembly process until a protective cover glass is mounted.

11.6.4 Compression force

A maximum compressive load of 25 N should be applied on the module.

11.6.5 Moisture sensitivity level

Moisture sensitivity is level 3 (MSL) as described in IPC/JEDEC JSTD-020-C.

Note: If devices are stored out of the packaging for greater than 168 h, the devices should be baked before use. The optimum bake recommended is at 90°C for a minimum of 6 hours.

11.7 Storage temperature conditions

Table 26. Recommended storage conditions

Parameter		Min.	Тур.	Max. Unit	
	Temperature (storage)	-40	23	90	°C

DS14310 - Rev 3 page 38/44



12 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

DS14310 - Rev 3 page 39/44



13 Ordering information

The VL53L8CH is currently available in the format below. More detailed information is available on request.

Table 27. Order codes

Order codes	Package	Packing	Minimum order quantity
VL53L8CHV0GC/1	Optical LGA16 with liner	Tape and reel	3600 pcs

DS14310 - Rev 3 page 40/44



Revision history

Table 28. Document revision history

Date	Version	Changes
22-Jun-2023	1	Initial release
	2	Added Section 1 Acronyms and abbreviations.
		Updated Figure 6. Typical application schematic for SPI.
27-Jul-2023		Added Table 13. Example of typical power consumption in continuous mode.
		Added values to Table 14. Example of typical power consumption in autonomous mode.
08-Aug-2023	3	Updated signal descriptions for C1 and C2 pins in Table 3. VL53L8CH pin description for I ² C and SPI configuration.

DS14310 - Rev 3 page 41/44



Contents

1 Acronyms and abbreviations					
2	Prod	duct ov	erview	4	
	2.1	Techn	ical specifications	4	
	2.2	Field o	of view	4	
	2.3	Field o	of illumination	5	
	2.4	Syster	m block diagram	6	
	2.5	Device	e pinout	6	
	2.6	Applic	cation schematics	8	
3	Fun	Functional description			
	3.1	Softwa	are interface	10	
	3.2	Power	r state machine	10	
	3.3	Power	r up sequence	11	
4	I ² C o	ontrol	interface	12	
	4.1	I ² C int	erface - timing characteristics	14	
5	SPI	timing	specification		
	5.1	SPI w	rite messages	17	
	5.2	SPI re	ead messages	18	
6	Elec	Electrical characteristics			
	6.1	Absolu	ute maximum ratings	19	
	6.2	Recon	mmended operating conditions	19	
	6.3	Electrostatic discharge (ESD)			
	6.4	Currer	nt consumption	20	
	6.5	Digital	I input and output	20	
7	Hist	ogram	(CNH) output	21	
8			erformances		
	8.1	Zone ı	mapping	23	
		8.1.1	Zone mapping 4x4		
		8.1.2	Zone mapping 8x8	23	
		8.1.3	Effective zone orientation	24	
	8.2	Contin	nuous ranging mode	24	
		8.2.1	Measurement conditions	24	
		8.2.2	Maximum ranging distance 4x4	25	
		8.2.3	Maximum ranging distance 8x8	25	
		8.2.4	Range accuracy in continuous mode	26	



	8.3	Autono	omous ranging mode	27		
		8.3.1	Measurement conditions	27		
		8.3.2	Maximum ranging distance 4x4	27		
		8.3.3	Maximum ranging distance 8x8	28		
		8.3.4	Range accuracy in autonomous mode	29		
	8.4	Range	offset drift over temperature	30		
9	Outli	ine drav	wings	31		
10	Lase	r safety	y considerations	34		
11	Pack	aging a	and labeling	35		
	11.1		ct marking			
	11.2		oox labeling			
	11.3					
	11.4					
	11.5	Pb-free solder reflow process				
	11.6	Handli	Handling and storage precautions			
		11.6.1	Recommended solder pad dimensions			
		11.6.2	Shock precautions	38		
		11.6.3	Part handling	38		
		11.6.4	Compression force	38		
		11.6.5	Moisture sensitivity level	38		
	11.7	Storag	e temperature conditions	38		
12	Pack	age inf	formation	39		
13	Orde	ering in	formation	40		
Rev	ision	historv		41		



IMPORTANT NOTICE - READ CAREFULLY

STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, enhancements, modifications, and improvements to ST products and/or to this document at any time without notice. Purchasers should obtain the latest relevant information on ST products before placing orders. ST products are sold pursuant to ST's terms and conditions of sale in place at the time of order acknowledgment.

Purchasers are solely responsible for the choice, selection, and use of ST products and ST assumes no liability for application assistance or the design of purchasers' products.

No license, express or implied, to any intellectual property right is granted by ST herein.

Resale of ST products with provisions different from the information set forth herein shall void any warranty granted by ST for such product.

ST and the ST logo are trademarks of ST. For additional information about ST trademarks, refer to www.st.com/trademarks. All other product or service names are the property of their respective owners.

Information in this document supersedes and replaces information previously supplied in any prior versions of this document.

© 2023 STMicroelectronics – All rights reserved

DS14310 - Rev 3 page 44/44